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Emergent ferromagnetism in ZnO/Al2O3 core-shell nanowires: Towards oxide spinterfaces

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We report that room-temperature ferromagnetism emerges at the interface formed between ZnO nanowire core and Al2O3 shell although both constituents show mainly diamagnetism. The interface-based ferromagnetism can be further enhanced by annealing the ZnO/Al2O3 core-shell nanowires and activating the formation of ZnAl2O4 phase as a result of interfacial solid-state reaction. High-temperature measurements indicate that the magnetic order is thermally stable up to 750 K. Transmission electron microscopy studies reveal the annealing-induced jagged interfaces, and the extensive structural defects appear to be relevant to the emergent magnetism. Our study suggests that tailoring the spinterfaces in nanostructure-harnessed wide-band-gap oxides is an effective route towards engineered nanoscale architecture with enhanced magnetic properties. © 2013 AIP Publishing LLC. [http://dx.doi.org/10.1063/1.4813217]

Bringing the spin degree of freedom into semiconductor devices has attracted much attention as a promising route towards semiconductor-based spintronics.1,2 As a prototypical oxide semiconductor, ZnO is an important wide-band-gap material with a large exciton binding energy (~60 meV), promising many applications in areas like optoelectronics and transparent electronics.3,4 Recently, there have been reports that ferromagnetism can be stabilized in transition (or rare-earth)-metal-doped ZnO,5–12 in spite of the fact that defect-free ZnO is nonmagnetic.13 However, the ferromagnetism in such doped oxides is generally rather weak, and the results are often controversial. It is clear that the conventional mechanisms such as the super- or double-exchange interactions cannot serve as the dominant scenario because the doping level is generally too low to produce a long-range magnetic order. On the other hand, there emerges a consensus that the magnetism in wide-band-gap oxides is often closely linked to the existence of structural impurities like point defects, grain boundaries, interfaces, and so on.14–20 In terms of mechanism, alternation of the electronic configuration, which is often a consequence of either intentional or unintentional structural/chemical inhomogeneity introduced in sample synthesis, has been proven as a viable approach to induce ferromagnetism.21–23 In particular, Coey et al. proposed that shallow donor electrons can form spin-split impurity bands and bound magnetic polarons.24 However, the main challenge remains regarding how to harness the oxide nanostructures to produce an enhanced and reliable magnetism in order to become relevant to practical spintronic devices.25

One viable approach of tailoring the magnetic order is to introduce interfaces between two different compounds in nanostructured oxide semiconductors. This approach is a drastic departure from the single-phase materials mostly reported in literature and offers additional advantages. In fact, constructing interfaces between two oxide materials, e.g., LaAlO3/SrTiO3,26 SrTiO3/KTaO3,27 and La2/3Ca1/3MnO3/MnO2/YBa2Cu3O7,28 have led to a surge of research interest in the study of magnetic and electronic properties of oxide interfaces. Recently, engineering the ZnO surface has played important roles in modulating the spin polarization and magnetic order in several material systems including ZnO nanostructures with organic molecule-passivation.21–23,25,29 In fact, Zn K-edge X-ray magnetic circular dichroism measurements revealed a ferromagnetic-like contribution from the interface formed between the ZnO nanoparticle core and the organic molecules.23 Similarly, spontaneous magnetization and hysteresis were observed in ZnO nanowires (NWs) modified with thiol-capped Ag nanoclusters30 and in ZnO/ZnS core-shell nanoparticles.31 Moreover, such a kind of “spinterfaces” was discovered at the interface of strained ZnO films grown on quartz substrates,32 where the structural strain was suggested to play an important role. It is also worth mentioning that, as a route to molecular spintronics, spinterfaces with a high degree of spin polarization were also investigated in the context of organic/metallic layers.33–35

In this Letter, we present an effective route towards the goal of enhanced magnetism by preparing and tailoring ZnO/Al2O3 (AZO) core-shell NWs, which have not only high surface-to-volume ratios but also large interface areas. The as-grown ZnO NWs showed a negligible magnetism as a result of high crystalline quality, whereas a clear ferromagnetic signal was detected after coating with a homogeneous Al2O3 outer shell, which can be further enhanced via annealing treatments. Our results suggest that nanoscale interface engineering and structural modification are effective to alter the local electronic and magnetic orders in core-shell NWs of wide-band-gap oxides and offer an alternative approach to produce magnetic nanostructures.
Single-crystal ZnO NWs were prepared in a horizontal tube furnace by means of vapor transport, and the experimental setup was described in previous reports. A homogeneous Al₂O₃ shell with various thicknesses was coated by using atomic layer deposition (ALD). In detail, the Si substrates covered with as-synthesized ZnO NWs were transferred to the ALD chamber [Beneq system (TFS 200)] and prebaked at 200°C for 60 min in vacuum (1.5 × 10⁻¹ Torr) with a steady Ar stream. The deposition took place at 200°C using trimethylaluminum [Al(CH₃)₃] and water as the aluminium and the oxygen sources, respectively. The thickness of the Al₂O₃ shell was controlled by the number of precursor/purge cycles. Some samples of ZnO/Al₂O₃ core-shell NWs were then annealed in air at 800°C for 3 h to activate the interfacial solid-state reaction. Magnetization measurements were performed on NW samples by using a superconducting quantum interference devices magnetometer (SQUID, Quantum Design, MPMSXL-5). Only plastic tweezers were used throughout all experiments to avoid any unintentional metal contamination. To determine the weight of NWs, the NWs were etched off after the SQUID experiments, and the substrate weight was accurately measured and deducted from the whole sample weight.

As shown in the field emission scanning electron microscopy (FESEM) image in Fig. 1(a), the as-grown ZnO NWs (sample uncoated ZnO (UZO)) on Si substrate have diameters of 50–100 nm and lengths of ~2 μm. The NWs became clearly thicker after a ~15 nm Al₂O₃ layer was coated (sample AZO) [Fig. 1(b)]. We further annealed the core-shell NWs in air at 800°C for 3 h. Interestingly, we found that the annealed ZnO/Al₂O₃ core-shell NWs (sample A-AZO) show very rough surfaces [Fig. 1(c)]. In the X-ray diffraction (XRD) patterns of the as-grown and the coated ZnO NWs [Fig. 1(d)], all peaks can be identified with the crystalline wurtzite ZnO structure, while the Al₂O₃ shell is amorphous. However, after annealing, ZnAl₂O₄ phase with the spinel structure notably emerged although its intensity is weak [Fig. 1(e)]. ZnAl₂O₄ is a well-known wide-band-gap semiconductor with an optical band gap of 3.8 eV, with applications such as photoelectronic devices. Thus, we can conclude that notable solid state reaction occurs in the interface areas by the annealing treatments.

Figure 2(a) depicts the M-H curves measured on UZO, AZO, and A-AZO at 5 and 300 K. The annealed sample A-AZO exhibits a much higher magnetism than the as-coated sample A-AZO, whereas the magnetism in the as-grown uncoated NW sample UZO is the weakest. In the data, the diamagnetic signal from Si substrates without NWs was carefully measured and then subtracted from the raw data [Fig. 2(b)]. The saturation magnetism of the sample A-AZO reaches 0.046 emu/g. Because the sample contains multiple compositions, we cannot accurately determine the magnetism in terms of formula unit. Nevertheless, the observed value of saturation magnetization in A-AZO is comparable to what reported for nanograined ZnO films (0.05 emu/g), but much higher than those of undoped ZnO nanoparticles obtained via chemical routes (between 0.0015 and 0.0022 emu/g) and ZnO nanorods (0.004 emu/g), as well as the thiol-capped ZnO nanoparticles (0.003 emu/g).

To find out the origin of magnetism in the annealed ZnO/Al₂O₃ core-shell NWs, we measured a control sample of ZnAl₂O₄ nanocrystals, which were fabricated using the conventional solid state reaction route from high-purity ZnO and Al₂O₃ powders, and found that ZnAl₂O₄ nanocrystals exhibit only a diamagnetic behavior [Fig. 2(c)]. Therefore, the enhanced magnetism in A-AZO cannot be attributed to the ZnAl₂O₄ nanocrystals alone formed at the ZnO/Al₂O₃ interface during annealing. Furthermore, we measured a few ZnO/Al₂O₃ NW samples with different thicknesses of Al₂O₃ shell, but did not find any considerable difference [Fig. 2(d)]. It further allows us to conclude that the observed ferromagnetism originates from ZnO/Al₂O₃ interfaces instead of the coated Al₂O₃ layers.

We measured the temperature dependent magnetization (M-T) curves of the ZnO/Al₂O₃ core-shell NW samples under a magnetic field of 500 Oe under both zero-field-cooled (ZFC) and field-cooled (FC) conditions. As shown in the inset of Fig. 2(e), in accordance with the M-H data, the temperature-dependent magnetization of A-AZO is much stronger than that of AZO. Furthermore, we carried out the high-temperature M-T experiments in an oven attached to the SQUID magnetometer, and as shown in Fig. 2(f), the magnetization of the sample A-AZO shows a transition close to 750 K, suggesting the magnetic order of the sample persists over a quite wide temperature range.

To understand the annealing-induced structural transformation at the interfaces within the ZnO/Al₂O₃ NWs, we carried out detailed transmission electron microscopy (TEM) experiments. As shown in Fig. 3(a), the as-grown ZnO NWs exhibit a single-crystal wurtzite structure and a [001] growth direction. After coating the amorphous alumina layer, the ZnO/Al₂O₃ core-shell structure was clearly observed, and there is no void or gap formed at the interface [Fig. 3(b)]. The local composition of the core-shell NWs was further confirmed in the energy-dispersive X-ray spectra with line scans of intensity profiles. Most importantly, after annealing treatment in air at 800°C for 3 h, significant solid state reactions occurred at the interface regions, and the surfaces of
the ZnO NWs become much rougher [Fig. 3(c)]. In the inset of Fig. 3(c), the ZnAl$_2$O$_4$ phase was clearly observed, which presumably resulted from nanoscale solid-state reaction between ZnO and Al$_2$O$_3$ within the NWs. The extensive high-resolution TEM (HRTEM) studies revealed the existence of lots of stacking faults and disordered structures in the interface areas [Fig. 3(d)]. It is important to note that nanoscale ZnAl$_2$O$_4$ phase have a good lattice match with the ZnO core, as suggested by the selective-area electron diffraction (SAED) pattern shown in the inset of Fig. 3(c), and the atomic stacking at the epitaxial interface is illustrated in Fig. 4(a). Our SAED results also suggest that the Al$_2$O$_3$ shell remains amorphous in all samples.

Our comparative structure-property studies on three kinds of NW samples revealed an intriguing interface-related origin of the ferromagnetism in wide-band-gap oxides without any intentional doping of transition metals. Ferromagnetism has been observed previously in undoped thin films and nanoparticles of TiO$_2$, HfO$_2$, In$_2$O$_3$, CaO, and CeO$_2$. This phenomenon is generally recognized as the d$^0$ magnetism, and its origin is usually linked to structural defects. But the d$^0$ magnetism is usually very weak, comparable to the magnetic signal observed in our as-grown ZnO NW sample (UZO). The SQUID data in Fig. 2 reveal a clear trend: The ferromagnetism can be enhanced by coating the ZnO NWs with a thin amorphous alumina layer (shown for the sample AZO), which can be further strengthened by the annealing treatment (shown for the sample A-AZO). It is in line with the findings by Garcia et al., where capping ZnO nanoparticles with different organic molecules was found to induce room-temperature ferromagnetic-like behaviors. In general, surfaces naturally break down the periodic boundary conditions which are assumed for ideal solids with infinite dimensions; thus, they are structural imperfection by themselves. Therefore, many structural motifs related to surfaces or grain boundaries can sustain a macroscopic magnetic order, particularly in nanomaterials.
In our annealed core-shell NWs, there are not only large-area surfaces but also extended jagged interfaces, which presumably contribute to the overall ferromagnetism. In the interface regions, unpaired electrons from the extended defect complexes may play important roles in establishing the local magnetic order, and the magnetic hysteresis is dominated by magnetic dipole interactions instead of the conventional magnetocrystalline anisotropy. It is not surprising that the electronic structure is severely altered on the nanoscale at the interfaces between the nanocrystalline ZnO, Al2O3, and ZnAl2O4 grains. Consequently, the unbalanced spin-dependent density of states at the Fermi surface gives rise to the observed magnetic moments. Furthermore, in ionic oxides like ZnO, the localized nature of the oxygen 2p states can lead to strong spin-exchange interactions, which may be further enhanced in nanomaterials.

Our design strategy towards magnetic nanostructures is illustrated in Fig. 4(b). It is important to note that local strain and structural imperfections are always abundantly present in the multi-phase nanostructures like the annealed core-shell NWs discussed here, and the complexity of electronic and magnetic orders is expected to result in interesting physical properties. On the other hand, it is clear that only a small portion of the synthesized materials, particularly near the interface areas, presents ferromagnetism, whereas the rest remains diamagnetic. In a recent x-ray spectroscopic study, we showed that most of transition metal ions in doped ZnO are antiferromagnetically coupled, contributing no macroscopic magnetism. In general, the magnetism and anisotropy in doped transition-metal oxides as a result of magnetic bond polarons are weak. Furthermore, in Co-doped ZnO nanostructures, and Co-doped TiO2 thin films, paramagnetism and superparamagnetism were observed and attributed to the formation of metallic nanoclusters. Nevertheless, the experimental revelation of the interface magnetism or “spinterface” in multi-component nanomaterials presented here clearly warrants further theoretical and spectroscopic investigations.

In summary, we presented our experimental results that the magnetic properties of undoped ZnO NWs can be significantly tailored and enhanced by forming core-shell nanostructures and conducting post-synthesis annealing treatments. The extended structural defects as well as the nanoscale formation of new ternary phases in the interface areas give rise to the alternation of local chemical and electronic configurations in such engineered oxide nanostructures. We hope that the demonstrated strategy of producing emergent magnetic order at the interfaces between nonmagnetic components of wide-band-gap oxides may stimulate the search for other oxide nanoscale architectures and devices with interesting properties.

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